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Team Nexperia

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

Rev. 8 — 14 November 2013

Product data sheet

1. Product profile

1.1 General description

NPN/PNP double Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1.	Product	overview

Type number			PNP/PNP	NPN/NPN	Package
	NXP	JEITA	complement complement c		configuration
PEMD2	SOT666	-	PEMB1	PEMH1	ultra small and flat lead
PIMD2	SOT457	SC-74	-	-	small
PUMD2	SOT363	SC-88	PUMB1	PUMH1	very small

1.2 Features and benefits

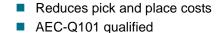
- 100 mA output current capability
 Reduces component count
- Built-in bias resistors
- Simplifies circuit design

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

1.4 Quick reference data

Quick reference data					
Parameter	Conditions	Min	Тур	Max	Unit
istor; for the PNP transistor	with negative p	olarity			
collector-emitter voltage	open base	-	-	50	V
output current		-	-	100	mA
bias resistor 1 (input)		15.4	22	28.6	kΩ
bias resistor ratio		0.8	1	1.2	
	Parameter istor; for the PNP transistor collector-emitter voltage output current bias resistor 1 (input)	ParameterConditionsistor; for the PNP transistor with negative por collector-emitter voltageopen baseoutput currentbias resistor 1 (input)	ParameterConditionsMinistor; for the PNP transistor with negative polaritycollector-emitter voltageopen base-output currentbias resistor 1 (input)15.4	ParameterConditionsMinTypistor; for the PNP transistor with negative polaritycollector-emitter voltageopen baseoutput currentbias resistor 1 (input)15.422	ParameterConditionsMinTypMaxistor; for the PNP transistor with negative polaritycollector-emitter voltageopen base50output current100bias resistor 1 (input)15.42228.6





NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
PEMD2	(SOT666); PUMD2 (SOT363)		
1	GND (emitter) TR1		
2	input (base) TR1	6 5 4	
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	output (collector) TR1	001aab555	

PIMD2 ((SOT457)		
1	GND (emitter) TR2		o
2	input (base) TR2		
3	output (collector) TR1	0	R1 R2
4	GND (emitter) TR1		
5	input (base) TR1		
6	output (collector) TR2		
			1 2 3

006aab235

2 3 006aaa143

1

3. Ordering information

Table 4. Ordering information					
Type number Package					
	Name	Description	Version		
PEMD2	-	plastic surface-mounted package; 6 leads	SOT666		
PIMD2	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457		
PUMD2	SC-88	plastic surface-mounted package; 6 leads	SOT363		

4. Marking

Table 5.	Marking codes	

Type number	Marking code ^[1]
PEMD2	D4
PIMD2	M5
PUMD2	D*2

[1] * = placeholder for manufacturing site code

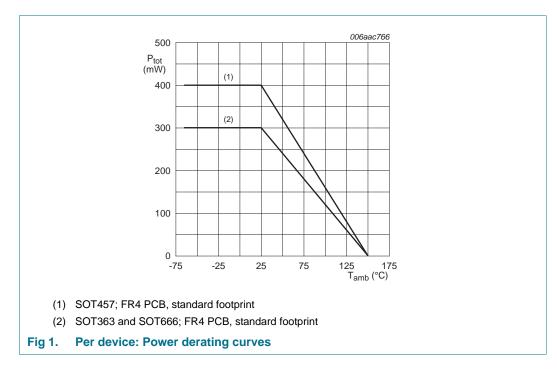
NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor; for the PNP transistor	with negative polarit	у		
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
VI	input voltage TR1				
	positive		-	+40	V
	negative		-	-10	V
	input voltage TR2				
	positive			+10	
	negative			-40	
lo	output current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 ms$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PEMD2 (SOT666)		<u>[1]</u> _	200	mW
	PIMD2 (SOT457)		<u>[1]</u>	250	mW
	PUMD2 (SOT363)		<u>[1]</u> _	200	mW
Per device	•				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PEMD2 (SOT666)		<u>[1]</u> _	300	mW
	PIMD2 (SOT457)		[1]	400	mW
	PUMD2 (SOT363)		<u>[1]</u> _	300	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

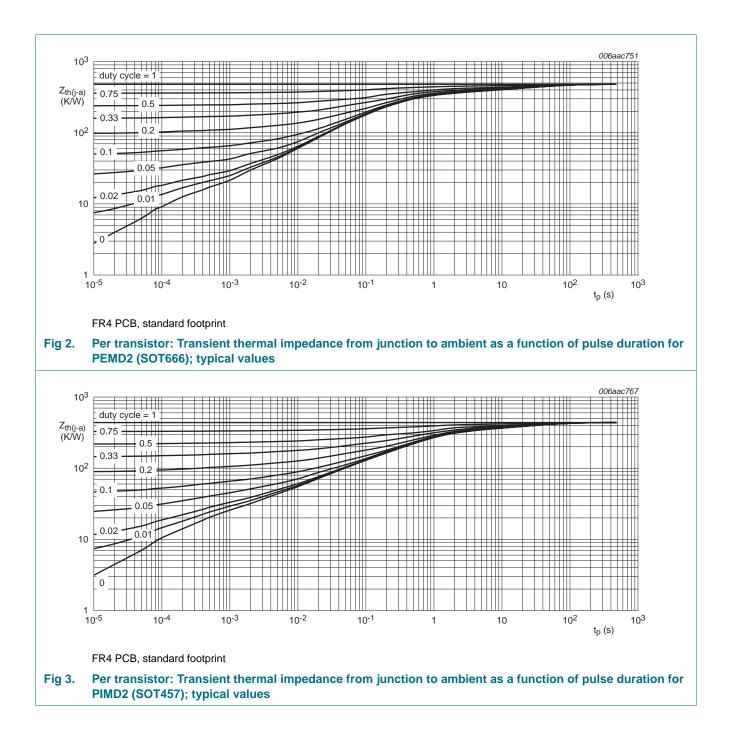


6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transis	stor					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PEMD2 (SOT666)		[1] -	-	625	K/W
	PIMD2 (SOT457)		[1] -	-	500	K/W
	PUMD2 (SOT363)		[1] -	-	625	K/W
Per device	;					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PEMD2 (SOT666)		<u>[1]</u> _	-	417	K/W
	PIMD2 (SOT457)		<u>[1]</u> _	-	313	K/W
	PUMD2 (SOT363)		<u>[1]</u> -	-	417	K/W

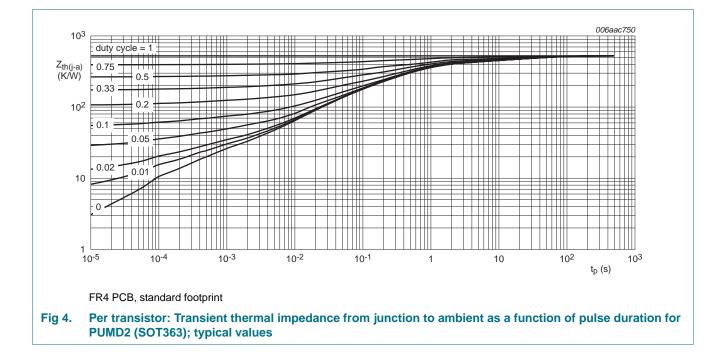
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

PEMD2; PIMD2; PUMD2



PEMD2; PIMD2; PUMD2

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



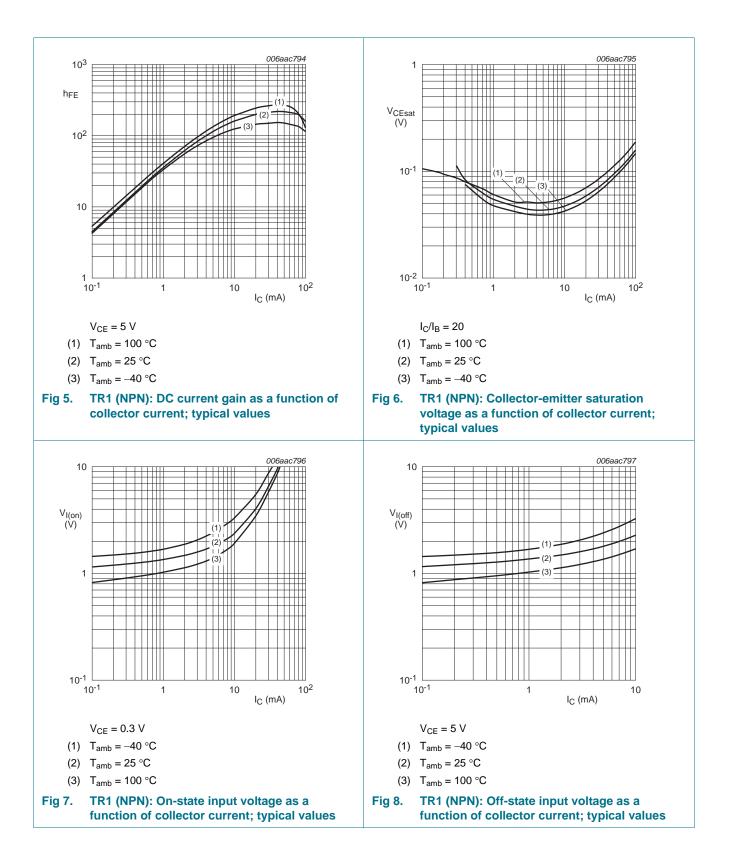
NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

7. Characteristics

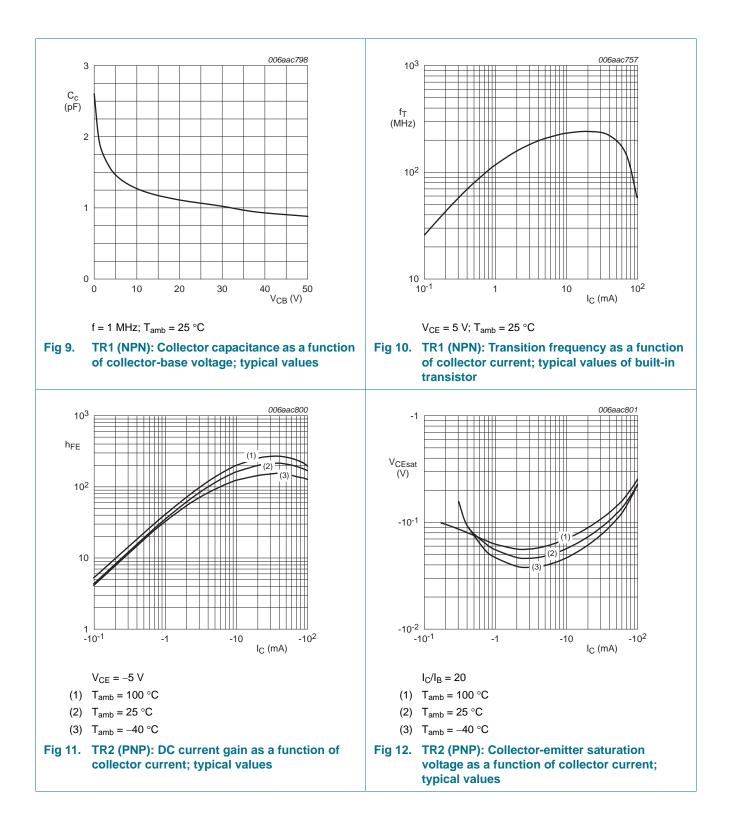
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	sistor; for the PNP trans	sistor with negative polarity				
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I _{CEO}	collector-emitter cut-off	$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	-	100	nA
	current	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 V; I_C = 0 A$	-	-	180	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	60	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 10 mA; I_{B} = 0.5 mA	-	-	150	mV
V _{I(off)}	off-state input voltage	V_{CE} = 5 V; I_C = 100 μ A	-	1.1	0.8	V
V _{I(on)}	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 5 \text{ mA}$	2.5	1.7	-	V
R1	bias resistor 1 (input)		15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	
C _c	collector capacitance	V_{CB} = 10 V; I_E = i_e = 0 A; f = 1 MHz				
	TR1 (NPN)		-	-	2.5	pF
	TR2 (PNP)		-	-	3	
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; [1] f = 100 MHz				
	TR1 (NPN)		-	230	-	MHz
	TR2 (PNP)		-	180	-	MHz

[1] Characteristics of built-in transistor

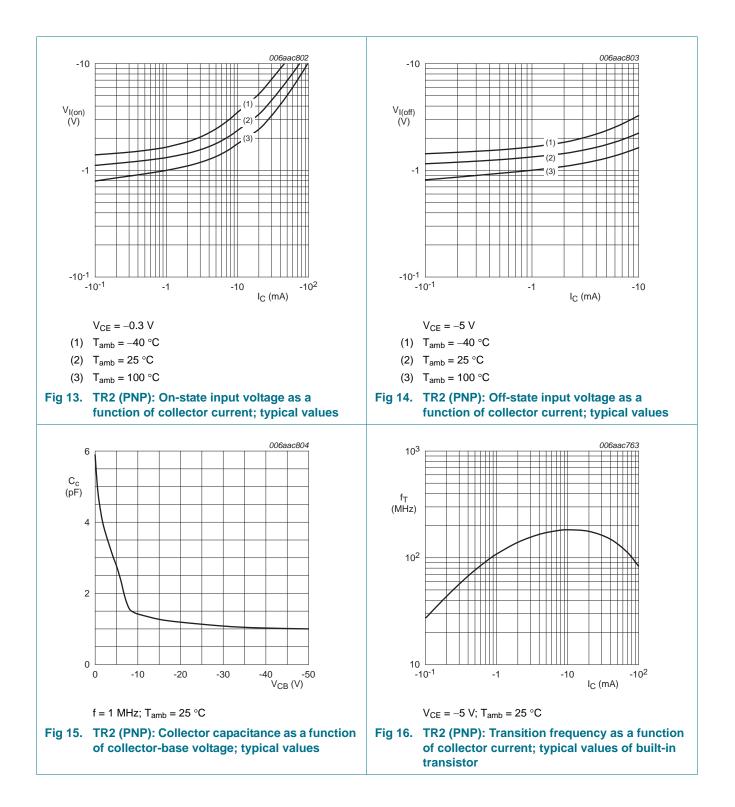
PEMD2; PIMD2; PUMD2



PEMD2; PIMD2; PUMD2



PEMD2; PIMD2; PUMD2



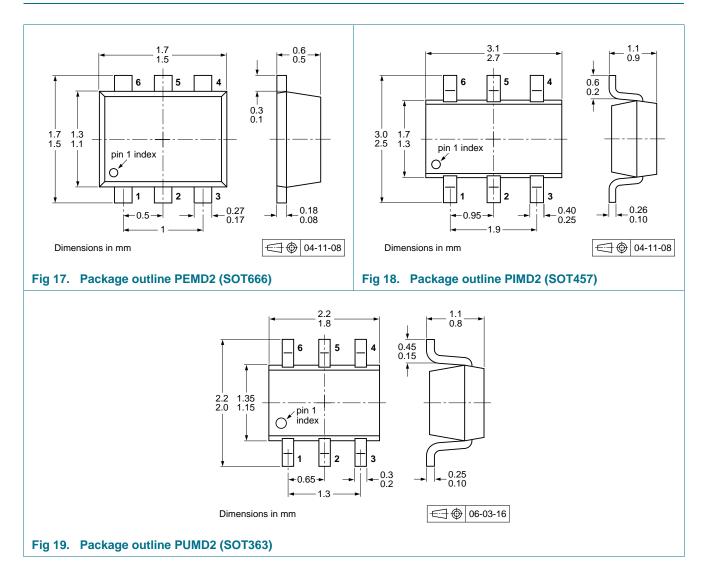
NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

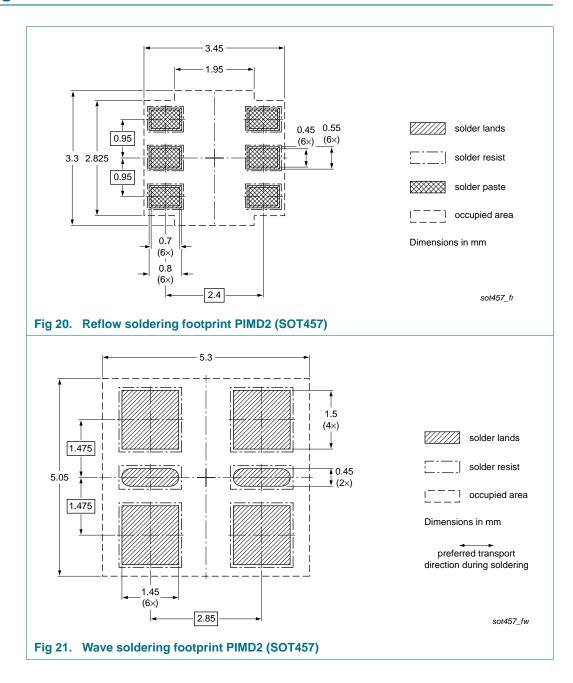
9. Package outline



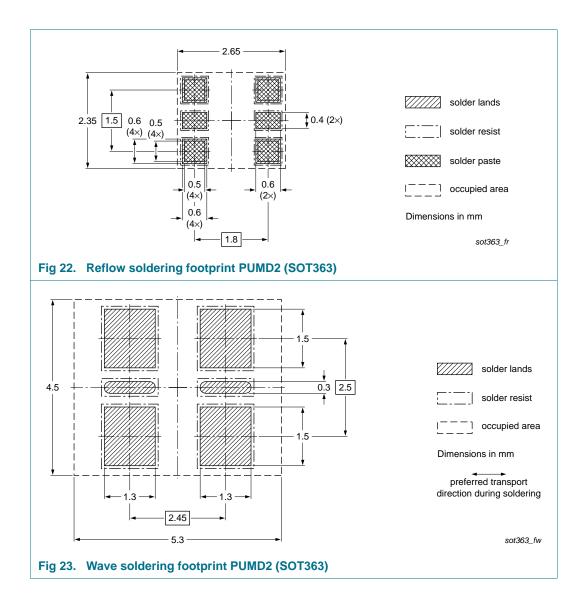
PEMD2_PIMD2_PUMD2

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

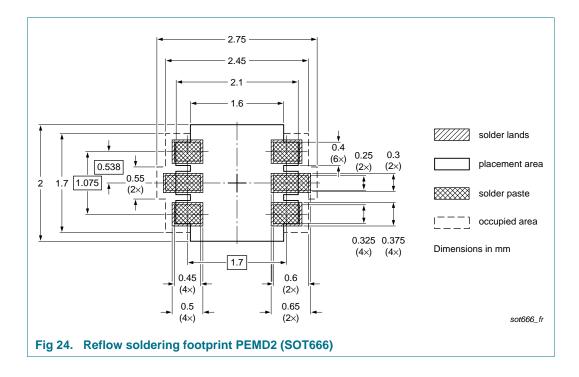
10. Soldering



NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

11. Revision history

Table 9.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PEMD2_PIMD2_PUMD2 v.8	20131114	Product data sheet	-	PEMD2_PIMD2_PUMD2 v.7
Modifications:	Section 1	"Product profile": updated	ł	
	Section 4 ⁶	"Marking": updated		
	 Figure 1 to 	9 <u>4, 9</u> , <u>10</u> , <u>15</u> and <u>16</u> : add	led	
	Section 5	"Limiting values": update	d	
	Section 6	"Thermal characteristics"	: updated	
	 Figure 5 to 	8 and <u>11</u> to <u>14</u> : updated		
	• Table 8 "C	haracteristics": I _{CEO} upda	ated, f _T added	
	Section 8	"Test information": added		
	Section 12	<u>2 "Legal information": upd</u>	ated	
PEMD2_PIMD2_PUMD2 v.7	20080924	Product data sheet	-	PEMD2_PIMD2_PUMD2 v.6
PEMD2_PIMD2_PUMD2 v.6	20042104	Product specification	-	PEMD2_PIMD2_PUMD2 v.5
PEMD2_PIMD2_PUMD2 v.5	20030606	Product specification	-	-

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PEMD2; PIMD2; PUMD2

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

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Date of release: 14 November 2013 Document identifier: PEMD2_PIMD2_PUMD2

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